



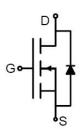
N-Channel Enhancement Mosfet

Feature

60V,20A

$$\begin{split} &R_{\text{DS (ON)}} <& 29 \text{m}\,\Omega\,\text{@V}_{\text{GS}} \text{=} 10 \text{V} \\ &R_{\text{DS (ON)}} <& 33 \text{m}\,\Omega\,\text{@V}_{\text{GS}} \text{=} 4.5 \text{V} \end{split} \qquad \begin{aligned} &\text{TYP:24 m}\,\Omega \end{aligned}$$

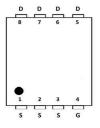
- Advanced Trench Technology
- Lead free product is acquired
- Excellent R DS (ON) and Low Gate Charge



Schematic Diagram

Application

- PWM applications
- Load Switch
- Power management
- Halogen-free



Pin Assignment

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
20N60	RM20N60D3	DFN3X3	13 inch	-	5000

ABSOLUTE MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current (T _C =25℃)	I _D	20	А
Continuous Drain Current (T _C =100℃)	I _D	14	А
Pulsed Drain Current (1)	I _{DM}	60	А
Single Pulsed Avalanche Energy (2)	E _{AS}	34	mJ
Power Dissipation	P _D	20	W
Thermal Resistance from Junction to Case	R _{θJC}	7.2	°C/W
Junction Temperature	TJ	150	$^{\circ}$ C
Storage Temperature	T _{STG}	-55~ +150	${\mathbb C}$

MOSFET ELECTRICAL CHARACTERISTICS(T_a=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Туре	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =-250μA	60	-	-	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =60V, V _{GS} = 0V	-	-	1	μΑ
Gate-body leakage current	I _{GSS}	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage ⁽³⁾	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250μA	1.1	1.6	2.2	V
Drain-source on-resistance ⁽³⁾	V(BR)DSS IDSS IGSS VGS(th) RDS(on) GFS Coss Crss Coss Crss Ud(onf) Uf Uf Ud(onf) Uf Uf Uf Uf Uf Uf Uf	V _{GS} =10V, I _D =15A	-	24	29	0
Drain-source on-resistance(**)		V _{GS} =4.5V, I _D =10A	-	28.5	33	mΩ
Forward tranconductance ⁽³⁾	g FS	V _{DS} =10V, I _D =15A	20	-	-	S
Dynamic characteristics						
Input Capacitance	C _{iss}		-	1090	-	
Output Capacitance	Coss	V _{DS} =25V, V _{GS} =0V, f =1MHz	-	56	-	pF
Reverse Transfer Capacitance	C _{rss}		-	47	-	
Switching characteristics	•					
Turn-on delay time	t _{d(on)}		-	7.2	-	
Turn-on rise time	t _r	_ V _{DD} =30V, I _D =20A	-	19	-	ns
Turn-off delay time	t _{d(off)}	V_{GS} =10V, R_G =1.8 Ω	-	14	-	
Turn-off fall time	t _f		-	22	-	
Total Gate Charge	Qg	\(\text{ID} \cdot \text{OO}\(\text{V} \text{ID} \cdot \text{OO}\(\text{A}\)	-	19.2	-	
Gate-Source Charge	arge Qgs VDS=30V, ID=10A,		-	3.6	-	nC
Gate-Drain Charge	Qgd	- VGS=10V	-	5.1	-	
Source-Drain Diode characteristics		•		•		
Diode Forward voltage ⁽³⁾	V _{DS}	V _{GS} =0V, I _S =15A	-	-	1.2	V
Diode Forward current ⁽⁴⁾	Is		-	-	20	Α
Body Diode Reverse Recovery Time	trr	T _J =25° , IF=20A,di/dt=100A/us		27		ns
Body Diode Reverse Recovery Charge	Qrr	T _J =25°, IF=20A,di/dt=100A/us		40		nc

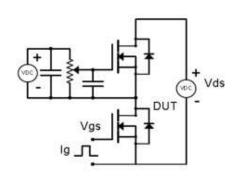
Notes:

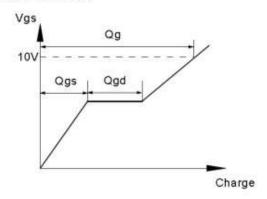
- 1. Repetitive Rating: pulse width limited by maximum junction temperature
- 2. EAS Condition:TJ=25 $^{\circ}$ C,VDD=30V,RG=25 $^{\Omega}$,L=0.5mH
- 3. Pulse Test: pulse width≤300µs, duty cycle≤2%
- 4. Surface Mounted on FR4 Board,t≤10 sec



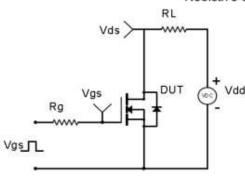
Test Circuit & Waveform

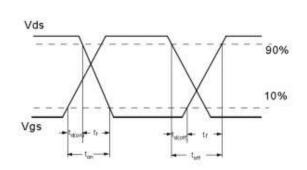
Gate Charge Test Circuit & Waveform



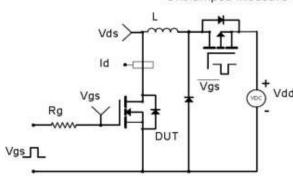


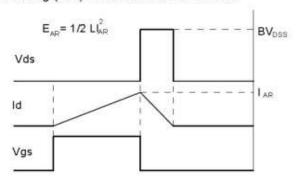
Resistive Switching Test Circuit & Waveforms



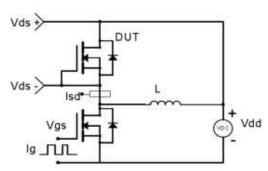


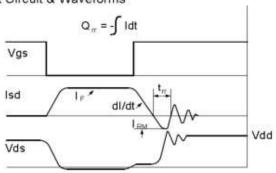
Unclamped Inductive Switching (UIS) Test Circuit & Waveforms





Diode Recovery Test Circuit & Waveforms







RATING AND CHARACTERISTICS CURVES (RM20N60D3)

Fig.1 Output Characteristics

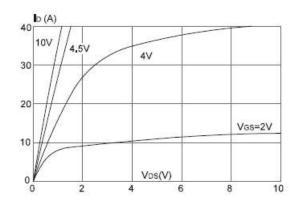


Fig.2 Typical Transfer Characteristics

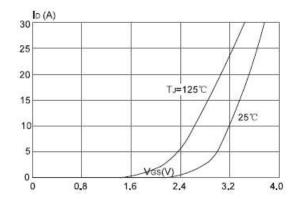


Fig.3 On-resistance VS Drain Current

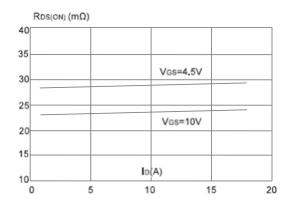


Fig. 4 Body Diode Characteristics

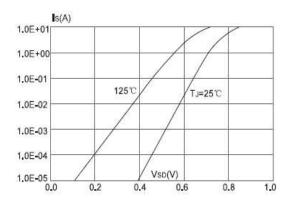


Fig.5 Gate Charge Characteristics

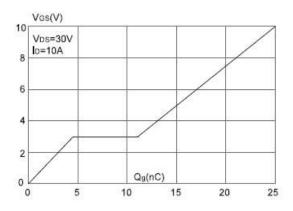
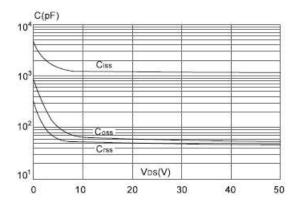


Fig. 6 Capacitance Characteristics





RATING AND CHARACTERISTICS CURVES (RM20N60D3)

VS Junction Temperature

VBR(DSS) 1.3 1.2 1.1 1.0 0.9 Tj (°C) -100 -50 0 50 100 150 200

Junction Temperature

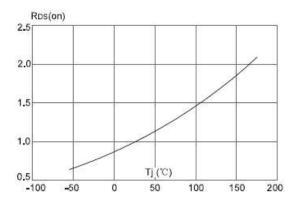
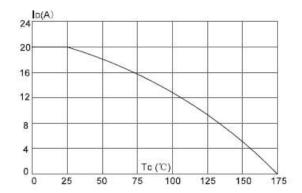


Fig.9 Maximum Continuous Drain Current VS. Case Temperature



RATING AND CHARACTERISTICS CURVES (RM20N60D3)

10³ Limited by RDS(on)

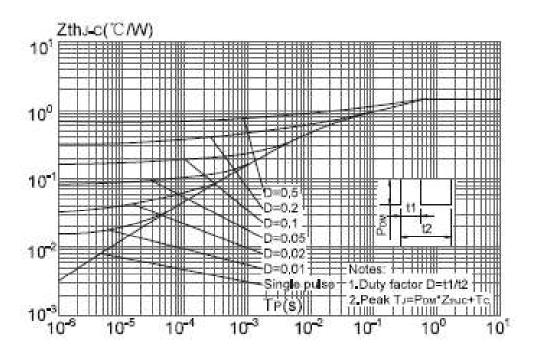
10² 10⁰ Tc=25 C 100ms

10⁰ Single pulse 100

0.1 1 10 100

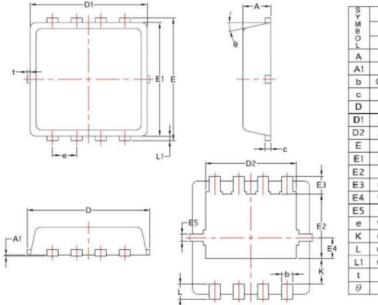
Fig.10 Safe Operating Area

Fig. 11 Transient Thermal Response Curve





DFN3X3 Package Information



S	COMMON					
M B	MM					
0	MIN	NOM	MAX			
A	0.70	0.75	0.85			
A1	1	/	0.05			
b	0.20	0.30	0.40			
С	0.10	0.152	0.25			
D	3.15	3.30	3.45			
D1	3.00	3.15	3.25			
D2	2.29	2.45	2.65			
E	3.15	3.30	3.45			
E١	2.90	3.05	3.20			
E2	1.54	1.74	1.94			
E3	0.28	0.48	0.65			
E4	0.37	0.57	0.77			
E5	0.10	0.20	0.30			
e	0.60	0.65	0.70			
K	0.59	0.69	0.89			
L	0.30	0.40	0.50			
L1	0.06	0.125	0.20			
t	0	0.075	0.13			
θ	10°	12°	14°			



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